

**BIPOLAR ANALOG INTEGRATED CIRCUIT**  
 **$\mu$ PC1251GR-9LG, 358GR-9LG**

**LOW POWER DUAL OPERATIONAL AMPLIFIERS**

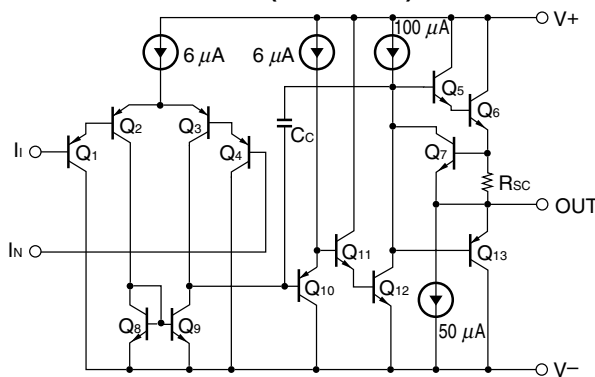
**DESCRIPTION**

The  $\mu$ PC1251GR-9LG, 358GR-9LG are dual operational amplifiers which are designed to operate from a single power supply over a wide range of voltages. Operation from split power supplies is also possible and the power supply current drain is very low. Further advantage, the input commonmode voltage range includes ground in the linear mode.

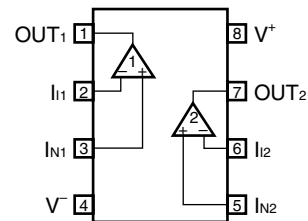
**FEATURES**

- Internally frequency compensation
- Wide output voltage swing  $V^-$  to  $V^+ - 1.5$  V
- Common mode input voltage range includes  $V^-$
- Wide supply voltage range
  - 3 V to 30 V (Single)
  - $\pm 1.5$  V to  $\pm 15$  V (Split)
- Output short circuit protection

**EQUIVALENT CIRCUIT (1/2 Circuit)**



**PIN CONFIGURATION (Marking Side)**



**ORDERING INFORMATION**

| Part Number             | Package                             |
|-------------------------|-------------------------------------|
| $\mu$ PC1251GR-9LG-A    | 8-pin plastic TSSOP (5.72 mm (225)) |
| $\mu$ PC1251GR(5)-9LG-A | 8-pin plastic TSSOP (5.72 mm (225)) |
| $\mu$ PC358GR-9LG-A     | 8-pin plastic TSSOP (5.72 mm (225)) |
| $\mu$ PC358GR(5)-9LG-A  | 8-pin plastic TSSOP (5.72 mm (225)) |

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**ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = 25°C)**

| Parameter   | Symbol                          | μPC1251GR-9LG                                | μPC358GR-9LG | Unit |
|---|---------------------------------|--|--------------|------|
| Voltage between V <sup>+</sup> and V <sup>-</sup> <sup>Note 1</sup> | V <sup>+</sup> - V <sup>-</sup> | -0.3 to +32                                  |              | V    |
| Differential Input Voltage  | V <sub>ID</sub>                 | ±32  |              | V    |
| Input Voltage <sup>Note 2</sup>                                     | V <sub>I</sub>                  | V <sup>-</sup> - 0.3 to V <sup>-</sup> + 32  |              | V    |
| Output Voltage <sup>Note 3</sup>                                    | V <sub>O</sub>                  | V <sup>-</sup> - 0.3 to V <sup>+</sup> + 0.3 |              | V    |
| Power Dissipation <sup>Note 4</sup>                                 | P <sub>T</sub>                  | 440  |              | mW   |
| Output Short Circuit Duration <sup>Note 5</sup>                     |                                 | Indefinite                                   |              | s    |
| Operating Ambient Temperature                                       | T <sub>A</sub>                  | -40 to +125                                  | -40 to +85   | °C   |
| Storage Temperature   | T <sub>stg</sub>                | -55 to +150                                  | -55 to +125  | °C   |

**Notes** 1. Reverse connection of supply voltage can cause destruction.

2. The input voltage should be allowed to input without damage or destruction independent of the magnitude of V<sup>+</sup>. Either input signal should not be allowed to go negative by more than 0.3 V. The normal operation will establish when the both inputs are within the Common Mode Input Voltage Range of electrical characteristics.

3. This specification is the voltage which should be allowed to supply to the output terminal from external without damage or destructive. Even during the transition period of supply voltage, power on/off etc., this specification should be kept. The output voltage of normal operation will be the Output Voltage Swing of electrical characteristics.

4. The thermal deleting factor of these IC are same value as -5.5mW/°C, but the delete beginning temperature in different as follows.

$$\mu\text{PC1251GR-9LG} : 69^{\circ}\text{C} \quad \mu\text{PC358GR-9LG} : 44^{\circ}\text{C}$$

The calculated junction to ambient thermal resistance at above conditions is 183°C/W.

5. Pay careful attention to the total power dissipation not to exceed the absolute maximum ratings, Note 4.

**RECOMMENDED OPERATING CONDITIONS**

| Parameter                             | Symbol         | MIN. | TYP. | MAX. | Unit |
|---------------------------------------|----------------|------|------|------|------|
| Supply Voltage (Split)                | V <sup>±</sup> | ±1.5 |      | ±15  | V    |
| Supply Voltage (V <sup>-</sup> = GND) | V <sup>+</sup> | +3   |      | +30  | V    |

μPC1251GR-9LG, μPC358GR-9LG

**ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25 °C, V<sup>+</sup> = +5 V, V<sup>-</sup> = GND)**

| Parameter                            | Symbol                | Conditions  | MIN. | TYP. | MAX.                 | Unit |
|--------------------------------------|-----------------------|---|------|------|----------------------|------|
| Input Offset Voltage                 | V <sub>IO</sub>       | R <sub>S</sub> = 0 Ω  |      | ±2   | ±7                   | mV   |
| Input Offset Current                 | I <sub>IO</sub>       |   |      | ±5   | ±50                  | nA   |
| Input Bias Current <sup>Note 6</sup> | I <sub>B</sub>        |   |      | 45   | 250                  | nA   |
| Large Signal Voltage Gain            | A <sub>V</sub>        | R <sub>L</sub> ≥ 2 kΩ   | 25   | 100  |                      | V/mA |
| Supply Current <sup>Note 7</sup>     | I <sub>CC</sub>       | R <sub>L</sub> = ∞, I <sub>O</sub> = 0 A  |      | 0.7  | 1.2                  | mA   |
| Common Mode Rejection Ratio          | CMR                   |   | 65   | 70   |                      | dB   |
| Supply Voltage Rejection Ratio       | SVR                   |   | 65   | 100  |                      | dB   |
| Output Voltage Swing                 | V <sub>O</sub>        | R <sub>L</sub> = 2 kΩ (Connect to GND)  | 0    |      | V <sup>+</sup> - 1.5 | V    |
| Common Mode Input Voltage Range      | V <sub>ICM</sub>      |   | 0    |      | V <sup>+</sup> - 1.5 | V    |
| Output Current (SOURCE)              | I <sub>O SOURCE</sub> | V <sub>IN<sup>+</sup></sub> = +1 V, V <sub>IN<sup>-</sup></sub> = 0 V                             | 20   | 40   |                      | mA   |
| Output Current (SINK)                | I <sub>O SINK</sub>   | V <sub>IN<sup>-</sup></sub> = +1 V, V <sub>IN<sup>+</sup></sub> = 0 V                             | 10   | 20   |                      | mA   |
|                                      |                       | V <sub>IN<sup>-</sup></sub> = +1 V, V <sub>IN<sup>+</sup></sub> = 0 V,<br>V <sub>O</sub> = 200 mV | 12   | 50   |                      | μA   |
| Channel Separation                   |                       | f = 1 kHz to 20 kHz   |      | 120  |                      | dB   |

**Notes 6.** Input bias currents flow out from IC. Because each currents are base current of PNP-transistor on input stage.

**7.** This current flows irrespective of the existence of use.

μPC1251GR(5)-9LG, μPC358GR(5)-9LG

**ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25 °C, V<sup>+</sup> = +5 V, V<sup>-</sup> = GND)**

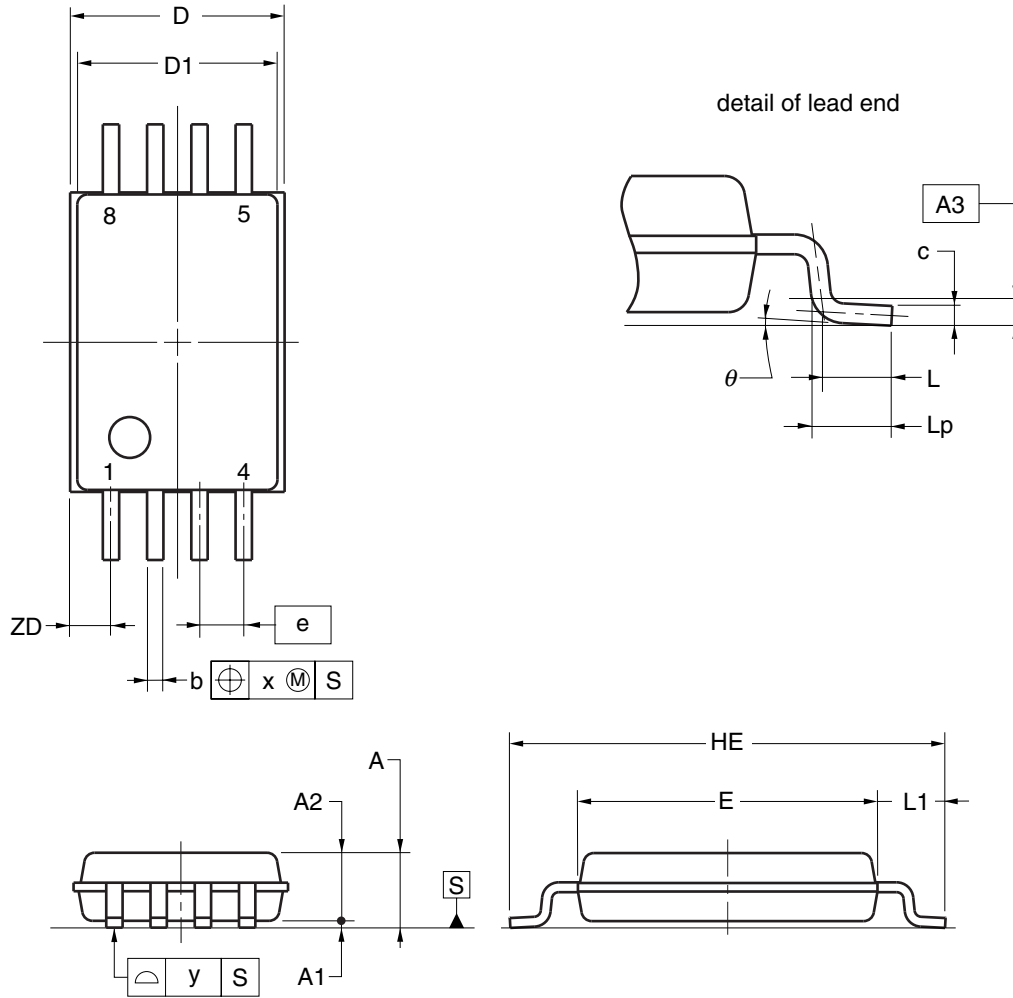
| Parameter                            | Symbol                | Conditions  | MIN. | TYP. | MAX.                 | Unit |
|--------------------------------------|-----------------------|---|------|------|----------------------|------|
| Input Offset Voltage                 | V <sub>IO</sub>       | R <sub>S</sub> = 0 Ω  |      | ±2   | ±3                   | mV   |
| Input Offset Current                 | I <sub>IO</sub>       |   |      | ±5   | ±50                  | nA   |
| Input Bias Current <sup>Note 6</sup> | I <sub>B</sub>        |   |      | 45   | 60                   | nA   |
| Large Signal Voltage Gain            | A <sub>V</sub>        | R <sub>L</sub> ≥ 2 kΩ   | 50   | 100  |                      | V/mA |
| Supply Current <sup>Note 7</sup>     | I <sub>CC</sub>       | R <sub>L</sub> = ∞, I <sub>O</sub> = 0 A  |      | 0.7  | 0.9                  | mA   |
| Common Mode Rejection Ratio          | CMR                   |   | 65   | 70   |                      | dB   |
| Supply Voltage Rejection Ratio       | SVR                   |   | 65   | 100  |                      | dB   |
| Output Voltage Swing                 | V <sub>O</sub>        | R <sub>L</sub> = 2 kΩ (Connect to GND)  | 0    |      | V <sup>+</sup> - 1.5 | V    |
| Common Mode Input Voltage Range      | V <sub>ICM</sub>      |   | 0    |      | V <sup>+</sup> - 1.4 | V    |
| Output Current (SOURCE)              | I <sub>O SOURCE</sub> | V <sub>IN<sup>+</sup></sub> = +1 V, V <sub>IN<sup>-</sup></sub> = 0 V                             | 30   | 40   |                      | mA   |
| Output Current (SINK)                | I <sub>O SINK</sub>   | V <sub>IN<sup>-</sup></sub> = +1 V, V <sub>IN<sup>+</sup></sub> = 0 V                             | 15   | 20   |                      | mA   |
|                                      |                       | V <sub>IN<sup>-</sup></sub> = +1 V, V <sub>IN<sup>+</sup></sub> = 0 V,<br>V <sub>O</sub> = 200 mV | 30   | 50   |                      | μA   |
| Channel Separation                   |                       | f = 1 kHz to 20 kHz   |      | 120  |                      | dB   |

**Notes 6.** Input bias currents flow out from IC. Because each currents are base current of PNP-transistor on input stage.

**7.** This current flows irrespective of the existence of use.

PACKAGE DRAWING

8-PIN PLASTIC TSSOP (5.72mm (225))



(UNIT:mm)

| ITEM | DIMENSIONS                             |
|------|--|
| D    | 3.15±0.15                              |
| D1   | 3.00±0.10                              |
| E    | 4.40±0.10                              |
| HE   | 6.40±0.20                              |
| A    | 1.20 MAX.                              |
| A1   | 0.10±0.05                              |
| A2   | 1.00±0.05                              |
| A3   | 0.25                                   |
| b    | 0.24 <sup>+0.06</sup> <sub>-0.05</sub> |
| c    | 0.145±0.055                            |
| L    | 0.50                                   |
| Lp   | 0.60±0.15                              |
| L1   | 1.00±0.20                              |
| θ    | 3° <sup>+5°</sup> <sub>-3°</sub>       |
| e    | 0.65                                   |
| x    | 0.10                                   |
| y    | 0.10                                   |
| ZD   | 0.60                                   |

P8GR-65-9LG

NOTE

Each lead centerline is located within 0.10mm of its true position at maximum material condition.

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**RECOMMENDED SOLDERING CONDITIONS**

The μPC1251GR-9LG, 358GR-9LG should be soldered and mounted under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact an NEC Electronics sales representative.

For technical information, see the following website.

**Semiconductor Device Mount Manual (<http://www.necel.com/pkg/en/mount/index.html>)**

**Type of Surface Mount Device**

| Process                | Conditions  | Symbol    |
|------------------------|---|-----------|
| Infrared ray reflow    | Peak temperature: 260 °C or below (Package surface temperature),<br>Reflow time: 60 seconds or less (at 220 °C or higher),<br>Maximum number of reflow processes: 3 time.                   | IR60-00-3 |
| Wave soldering         | Solder temperature: 260 °C or below, Flow time: 10 seconds or less,<br>Maximum number of flow processes: 1 time,<br>Pre-heating temperature: 120 °C or below (Package surface temperature). | WS60-00-1 |
| Partial heating method | Pin temperature: 350 °C or below,<br>Heat time: 3 seconds or less (Per each side of the device).  | P350      |

**Caution** Apply only one kind of soldering condition to a device, except for “partial heating method”, or the device will be damaged by heat stress.

**REFERENCE DOCUMENTS**

| Document Name   | Document No.  |
|---|---|
| QUALITY GRADES ON NEC SEMICONDUCTOR DEVICES   | C11531E   |
| SEMICONDUCTOR DEVICE MOUNT MANUAL   | <a href="http://www.necel.com/pkg/en/mount/index.html">http://www.necel.com/pkg/en/mount/index.html</a> |
| NEC SEMICONDUCTOR DEVICE RELIABILITY/QUALITY CONTROL SYSTEM<br>- STANDARD LINEAR IC | IEI-1212  |

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